



4.00"(101.60mm)Dual Digit 7 Segment Display

Features:

- *High segment intensity
- *Wide viewing angle
- *Range of colors
- *Gray face White segment
- *RoHS compliant

Available option:

- *Available emitting color
- *Available Segment color
- *Low current version

Electro/Optical Characteristics If=20mA Ta=25°C

Part Number Common Cathode	Part Number Common Anode	Emitting Color	Peak Wavelength	Forward Voltage V _F /Seg.(DP)		Luminous Intensity I _v /seg.(DP)	
				Typ.	Max.	Min.	Typ.
	NFD-40021BUB-21	InGaN/SiC Ultra Blue	470	14.00(7.00)	16.00(8.00)	320.00(80.00)	480.00(120.00)
	NFD-40021BS-21	GaAlAs/GaAs SH Hi-Red	660	7.20(3.60)	8.80(4.40)	64.00(16.00)	96.00(24.00)
	NFD-40021BD-21	GaAlAs/GaAs DH Super Red	660	7.20(3.60)	8.80(4.40)	176.00(44.00)	224.00(56.00)
	NFD-40021BE-21	GaAsP/GaP Orange	632	8.40(4.20)	10.00(5.00)	64.00(16.00)	96.00(24.00)
	NFD-40021BY-21	GaAsP/GaP Yellow	585	8.40(4.20)	10.00(5.00)	32.00(8.00)	56.00(14.00)
	NFD-40021BG-21	GaP/GaP Green	568	8.80(4.40)	10.00(5.00)	56.00(14.00)	88.00(22.00)
Units			nm	V		mcd	

Maximum Ratings Ta=25°C (Derate above 25°C)

Characteristic	Test Condition	Symbol	UB	S	D	E	Y	G	Units
Pulse Forward Current Per Seg.	1/10 duty cycle 0.1ms Pulse width	I _{FP}	100*2(100)	100*2(100)	100*2(100)	100*2(100)	100*2(100)	100*2(100)	mA
DC Forward Current Per Seg.		I _F	30*2(30)	25*2(25)	25*2(25)	30*2(30)	30*2(30)	30*2(30)	mA
Reverse Current Per Seg.	V _R =10V	I _R	10	10	10	10	10	10	μA
Power Dissipation		P _D	120*116	60*116	60*116	80*116	80*116	80*116	mW
Operating Temperature		T _{OPR}	-40 to +80						°C
Storage Temperature		T _{TSG}	-40 to +85						°C
Lead soldering temperature	1.60mm from body maximum 3 seconds		260						°C

Checked

Chen N.H.

Approved

Jason Chen

Date

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